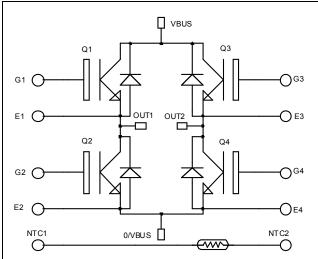
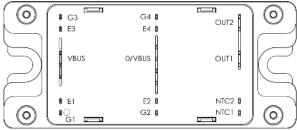


Full bridge High speed Trench + Field Stop IGBT4 Power Module





(o) **₿** G3 G4 🛭



Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- Kelvin emitter for easy drive
- Very low stray inductance
- Lead frames for power connections
- Internal thermistor for temperature monitoring

Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- Low profile
- **RoHS Compliant**

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
Ţ	Continuous Collector Current	$T_C = 25$ °C	130	
I_{C}	Continuous Conector Current T _C :	$T_C = 80$ °C	75	Α
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	250	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Power Dissipation		385	W

🗱 🗱 UTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				50	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.78	2.05	2.4	V
		$I_C = 75A$ $T_j = 15$	$T_{j} = 150^{\circ}C$		2.6		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 2.6 \text{ mA}$		5.3	5.8	6.3	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				150	nA

Dynamic Characteristics (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			4400		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			250		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			235		
Q_{G}	Gate charge	$V_{GE} = 15V, I_C = 75A$ $V_{CE} = 960V$			325		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Swit	Inductive Switching (25°C)		30		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			57		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 75A$			290		
T_{f}	Fall Time	$R_G = 7\Omega$		16			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)			30		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			49		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 75A$ $R_{G} = 7\Omega$			366		ns
T_{f}	Fall Time				48		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 150$ °C		6.4		mJ
E_{off}	Turn off Energy	$I_{\rm C} = 75A$ $R_{\rm G} = 7\Omega$	$T_j = 150$ °C		3.8		1113
R_G	Integrated gate resistor				10		Ω
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 600V$ $t_p \le 10\mu s$; $T_i = 150$ °C			260		A
R_{thJC}	Junction to Case Thermal Resistance		•			0.39	°C/W

Diode ratings and characteristics (per diode)

Symbol	Characteristic Test Conditions		Min	Typ	Max	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	V _R =1200V				150	μΑ
I_F	DC Forward Current		Tc = 60°C		60		A
		$I_F = 60A$			2.6	3.5	
V_{F}	Diode Forward Voltage	$I_F = 120A$			3.2		V
		$I_F = 60A$	$T_{j} = 125^{\circ}C$		1.8		
+	IF OUA		$T_j = 25$ °C		300		13 .0
t_{rr}		$T_{j} = 125^{\circ}C$		380		ns	
Q _{rr} I	Reverse Recovery Charge	$V_{R} = 800V$ $di/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		720		пC
			$T_{j} = 125^{\circ}C$		3400		пС
R_{thJC}	Junction to Case Thermal Resistance					0.65	°C/W



$\label{thm:complex} \textbf{Temperature sensor NTC} \ \ (\text{see application note APT0406 on www.microsemi.com}).$

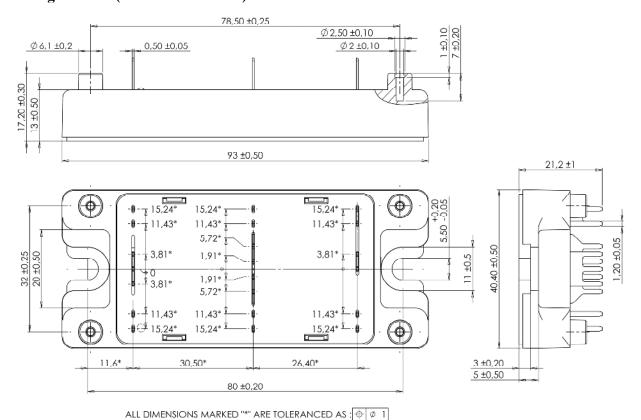
Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
T_{J}	Operating junction temperature range			-40	175	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	C
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M5	2.5	4.7	N.m
Wt	Package Weight				160	g

Package outline (dimensions in mm)

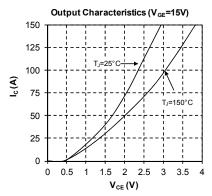


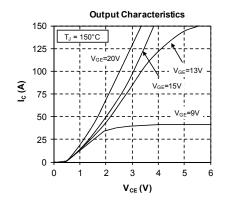
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

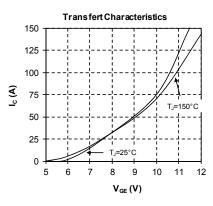
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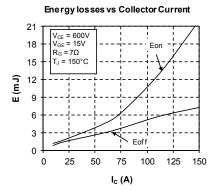


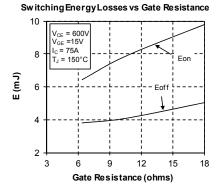
Typical performance curve

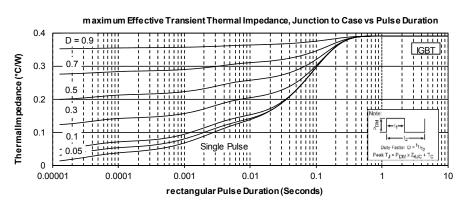






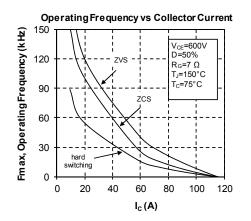


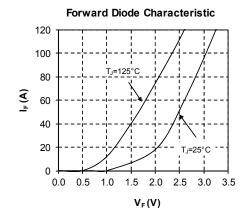




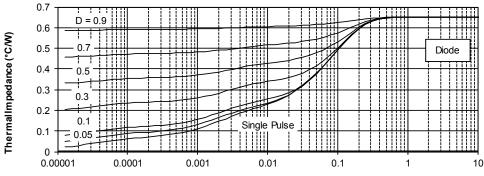


Power Matters."





maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



www.microsemi.com

Rectangular Pulse Duration (Seconds)

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